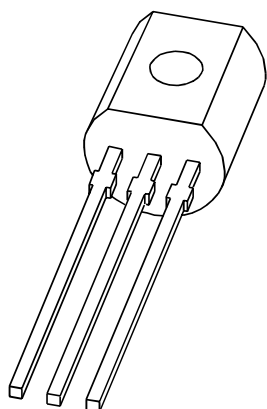


# DATA SHEET



## **PH2222; PH2222A** NPN switching transistors

Product specification  
Supersedes data of 1997 May 20  
File under Discrete Semiconductors, SC04

1997 Sep 04

# NPN switching transistors

# PH2222; PH2222A

### FEATURES

- High current (max. 600 mA)
- Low voltage (max. 40 V).

### APPLICATIONS

- Switching and linear amplification.

### DESCRIPTION

NPN switching transistor in a TO-92; SOT54 plastic package. PNP complement: PH2907 and PH2907A.

### PINNING

PIN	DESCRIPTION
1	emitter
2	base
3	collector

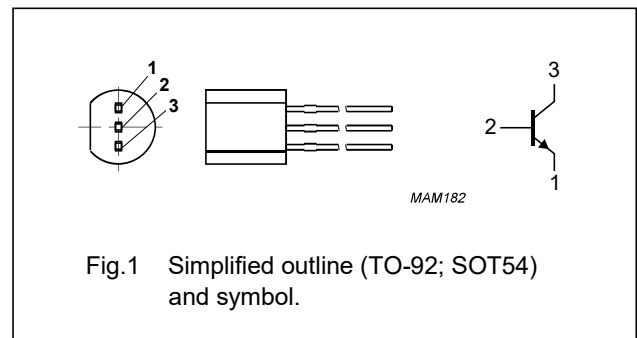


Fig. 1 Simplified outline (TO-92; SOT54) and symbol.

### QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
$V_{CBO}$	collector-base voltage	open emitter			
	PH2222		–	60	V
	PH2222A		–	75	V
$V_{CEO}$	collector-emitter voltage	open base			
	PH2222		–	30	V
	PH2222A		–	40	V
$I_C$	collector current (DC)		–	600	mA
$P_{tot}$	total power dissipation	$T_{amb} \leq 25\text{ }^\circ\text{C}$	–	500	mW
$h_{FE}$	DC current gain	$I_C = 10\text{ mA}; V_{CE} = 10\text{ V}$	75	–	
$f_T$	transition frequency	$I_C = 20\text{ mA}; V_{CE} = 20\text{ V}; f = 100\text{ MHz}$			
	PH2222		250	–	MHz
	PH2222A		300	–	MHz
$t_{off}$	turn-off time	$I_{Con} = 150\text{ mA}; I_{Bon} = 15\text{ mA}; I_{Boff} = -15\text{ mA}$	–	250	ns

## NPN switching transistors

## PH2222; PH2222A

**LIMITING VALUES**

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V <sub>CBO</sub>	collector-base voltage	open emitter			
	PH2222		–	60	V
	PH2222A	–	75	V	
V <sub>CEO</sub>	collector-emitter voltage	open base			
	PH2222		–	30	V
	PH2222A	–	40	V	
V <sub>EBO</sub>	emitter-base voltage	open collector			
	PH2222		–	5	V
	PH2222A	–	6	V	
I <sub>C</sub>	collector current (DC)		–	600	mA
I <sub>CM</sub>	peak collector current		–	800	mA
I <sub>BM</sub>	peak base current		–	200	mA
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> ≤ 25 °C	–	500	mW
T <sub>stg</sub>	storage temperature		–65	+150	°C
T <sub>j</sub>	junction temperature		–	150	°C
T <sub>amb</sub>	operating ambient temperature		–65	+150	°C

**THERMAL CHARACTERISTICS**

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R <sub>th j-a</sub>	thermal resistance from junction to ambient	note 1	250	K/W

**Note**

1. Transistor mounted on an FR4 printed-circuit board.

## NPN switching transistors

## PH2222; PH2222A

**CHARACTERISTICS**

$T_j = 25\text{ °C}$  unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
$I_{CBO}$	collector cut-off current PH2222	$I_E = 0; V_{CB} = 50\text{ V}$	–	10	nA
		$I_E = 0; V_{CB} = 50\text{ V}; T_{amb} = 150\text{ °C}$	–	10	$\mu\text{A}$
$I_{CBO}$	collector cut-off current PH2222A	$I_E = 0; V_{CB} = 60\text{ V}$	–	10	nA
		$I_E = 0; V_{CB} = 60\text{ V}; T_{amb} = 150\text{ °C}$	–	10	$\mu\text{A}$
$I_{EBO}$	emitter cut-off current	$I_C = 0; V_{EB} = 3\text{ V}$	–	10	nA
$h_{FE}$	DC current gain	$I_C = 0.1\text{ mA}; V_{CE} = 10\text{ V}$	35	–	
		$I_C = 1\text{ mA}; V_{CE} = 10\text{ V}$	50	–	
		$I_C = 10\text{ mA}; V_{CE} = 10\text{ V}$	75	–	
		$I_C = 150\text{ mA}; V_{CE} = 1\text{ V}; \text{note 1}$	50	–	
		$I_C = 150\text{ mA}; V_{CE} = 10\text{ V}; \text{note 1}$	100	300	
$h_{FE}$	DC current gain PH2222A	$I_C = 10\text{ mA}; V_{CE} = 10\text{ V}; T_{amb} = -55\text{ °C}$	35	–	
$h_{FE}$	DC current gain PH2222 PH2222A	$I_C = 500\text{ mA}; V_{CE} = 10\text{ V}; \text{note 1}$	30	–	
			40	–	
$V_{CEsat}$	collector-emitter saturation voltage PH2222 PH2222A	$I_C = 150\text{ mA}; I_B = 15\text{ mA}; \text{note 1}$	–	400	mV
			–	300	mV
$V_{CEsat}$	collector-emitter saturation voltage PH2222 PH2222A	$I_C = 500\text{ mA}; I_B = 50\text{ mA}; \text{note 1}$	–	1.6	V
			–	1	V
$V_{BEsat}$	base-emitter saturation voltage PH2222 PH2222A	$I_C = 150\text{ mA}; I_B = 15\text{ mA}; \text{note 1}$	–	1.3	V
			0.6	1.2	V
$V_{BEsat}$	base-emitter saturation voltage PH2222 PH2222A	$I_C = 500\text{ mA}; I_B = 50\text{ mA}; \text{note 1}$	–	2.6	V
			–	2	V
$C_c$	collector capacitance	$I_E = i_e = 0; V_{CB} = 10\text{ V}; f = 1\text{ MHz}$	–	8	pF
$C_e$	emitter capacitance PH2222A	$I_C = i_c = 0; V_{EB} = 500\text{ mV}; f = 1\text{ MHz}$	–	25	pF
$f_T$	transition frequency PH2222 PH2222A	$I_C = 20\text{ mA}; V_{CE} = 20\text{ V}; f = 100\text{ MHz}$	250	–	MHz
			300	–	MHz
F	noise figure PH2222A	$I_C = 200\text{ }\mu\text{A}; V_{CE} = 5\text{ V}; R_S = 2\text{ k}\Omega;$ $f = 1\text{ kHz}; B = 200\text{ Hz}$	–	4	db

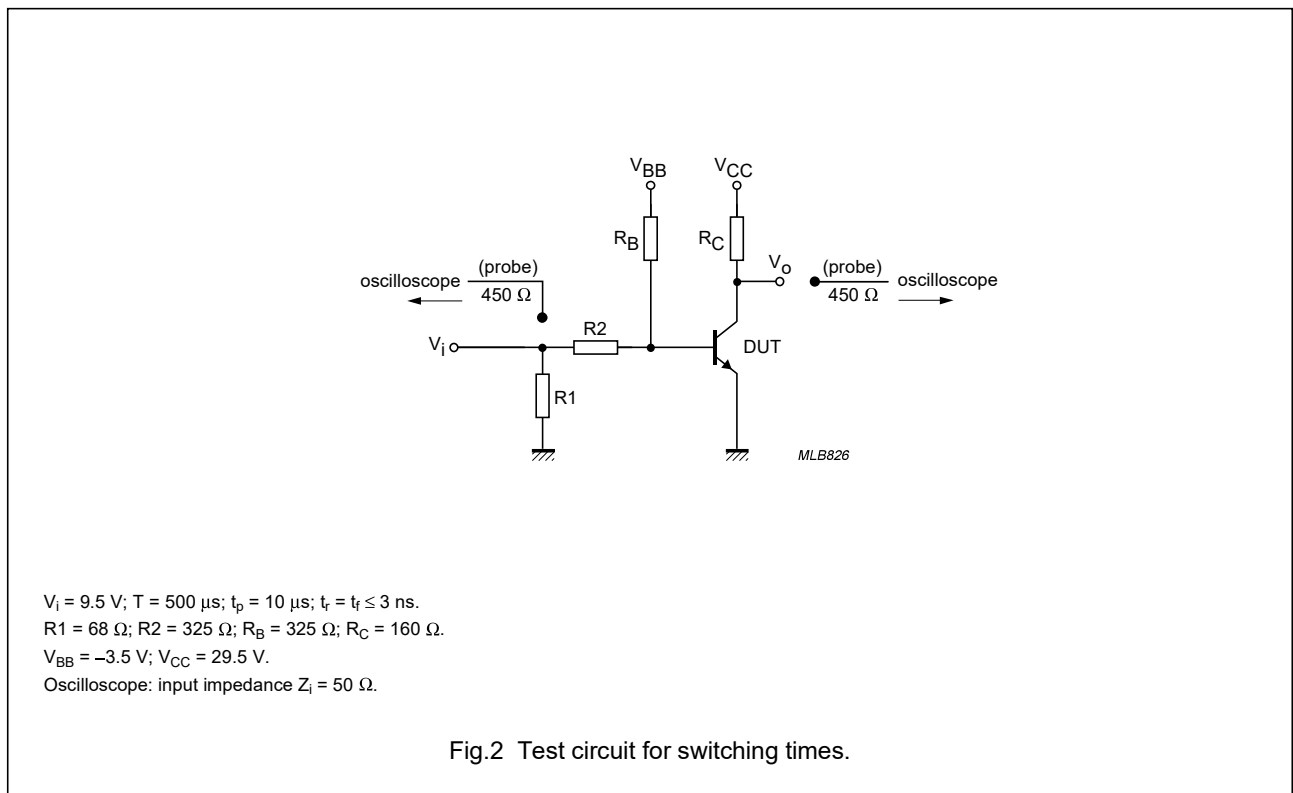
NPN switching transistors

PH2222; PH2222A

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
<b>Switching times (between 10% and 90% levels); see Fig.2</b>					
$t_{on}$	turn-on time	$I_{Con} = 150 \text{ mA}; I_{Bon} = 15 \text{ mA};$ $I_{Boff} = -15 \text{ mA}$	–	35	ns
$t_d$	delay time		–	15	ns
$t_r$	rise time		–	20	ns
$t_{off}$	turn-off time		–	250	ns
$t_s$	storage time		–	200	ns
$t_f$	fall time		–	60	ns

**Note**

1. Pulse test:  $t_p \leq 300 \mu\text{s}; \delta \leq 0.02$ .



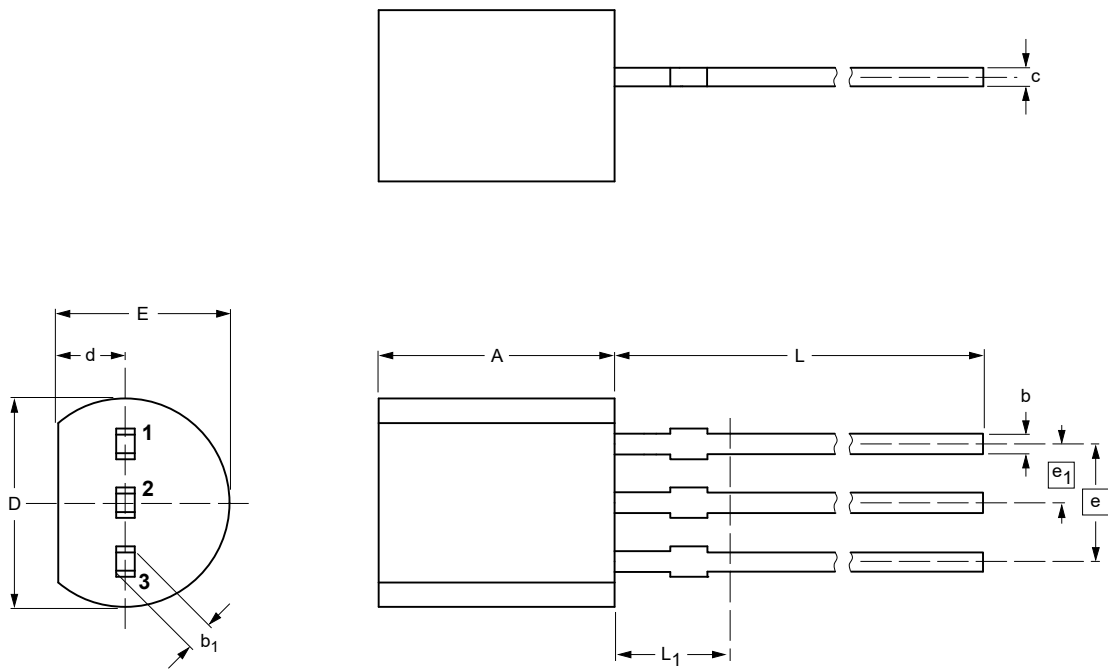
NPN switching transistors

PH2222; PH2222A

PACKAGE OUTLINE

Plastic single-ended leaded (through hole) package; 3 leads

SOT54



DIMENSIONS (mm are the original dimensions)

UNIT	A	b	b <sub>1</sub>	c	D	d	E	e	e <sub>1</sub>	L	L <sub>1</sub> <sup>(1)</sup>
mm	5.2	0.48	0.66	0.45	4.8	1.7	4.2	2.54	1.27	14.5	2.5
	5.0	0.40	0.56	0.40	4.4	1.4	3.6				

Note

1. Terminal dimensions within this zone are uncontrolled to allow for flow of plastic and terminal irregularities.

OUTLINE VERSION	REFERENCES			EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	EIAJ		
SOT54		TO-92	SC-43		97-02-28

## NPN switching transistors

PH2222; PH2222A

**DEFINITIONS**

<b>Data sheet status</b>	
Objective specification	This data sheet contains target or goal specifications for product development.
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.
Product specification	This data sheet contains final product specifications.
<b>Limiting values</b>	
Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.	
<b>Application information</b>	
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